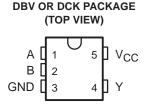
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- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- Operating Range 2-V to 5.5-V V_{CC}
- Package Options Include Plastic Small-Outline Transistor (DBV, DCK) Packages



description

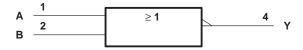
This device contains a single 2-input NOR gate that performs the Boolean function $Y = \overline{A} \bullet \overline{B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

The SN74AHC1G02 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE

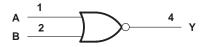
INP	UTS	OUTPUT
Α	В	Υ
Н	Х	L
Х	Н	L
L	L	Н

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (see Note 1)	0.5 V to 7 V
Output voltage range, VO (see Note 1)	
Input clamp current, I _{IK} (V _I < 0)	–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±25 mA
Continuous current through V _{CC} or GND	±50 mA
Package thermal impedance, θ _{JA} (see Note 2): DBV package	347°C/W
DCK package	389°C/W
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
VCC	Supply voltage		2	5.5	V
		V _{CC} = 2 V	1.5		
V_{IH}	High-level input voltage VCC = 3 V	2.1		V	
		V _{CC} = 5.5 V	3.85		
		V _{CC} = 2 V		0.5	
V_{IL}	Low-level input voltage	V _{CC} = 3 V		0.9	V
		V _{CC} = 5.5 V		1.65	
٧ _I	Input voltage		0	5.5	V
Vo	Output voltage		0	VCC	V
		V _{CC} = 2 V		-50	μΑ
IOH	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	A
		$V_{CC} = 5 V \pm 0.5 V$		-8	mA
		V _{CC} = 2 V		50	μΑ
IOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	A
		$V_{CC} = 5 V \pm 0.5 V$		8	mA
A4/A	lands transition via a refall rate	V _{CC} = 3.3 V ± 0.3 V		100	− ns/V
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		20	
TA	Operating free-air temperature		-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Voc	T _A = 25°C			MIN	MAX	UNIT	
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	IVIIIV	WAX	UNII	
		2 V	1.9	2		1.9			
	I _{OH} = -50 μA	3 V	2.9	3		2.9			
Voн		4.5 V	4.4	4.5		4.4		V	
	I _{OH} = -4 mA	3 V	2.58			2.48			
	I _{OH} = -8 mA	4.5 V	3.94			3.8		<u> </u>	
		2 V			0.1		0.1		
	I _{OL} = 50 μA	3 V			0.1		0.1		
V _{OL}		4.5 V			0.1		0.1	V	
	I _{OL} = 4 mA	3 V			0.36		0.44		
	I _{OL} = 8 mA	4.5 V			0.36		0.44		
Ι _Ι	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1		±1	μΑ	
lcc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			1		10	μΑ	
C _i	$V_I = V_{CC}$ or GND	5 V		4	10		10	pF	

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT
FARAMETER				MIN	TYP	MAX	IVIIIV	IWAA	CIVIT
^t PLH	A or B	A or P	Y C _L = 15 pF		5.6	7.9	1	9.5	no
t _{PHL}	AUIB	ī			5.6	7.9	1	9.5	ns
^t PLH	A or B	V	Y		8.1	11.4	1	13	no
t _{PHL}	AUIB	ī			8.1	11.4	1	13	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

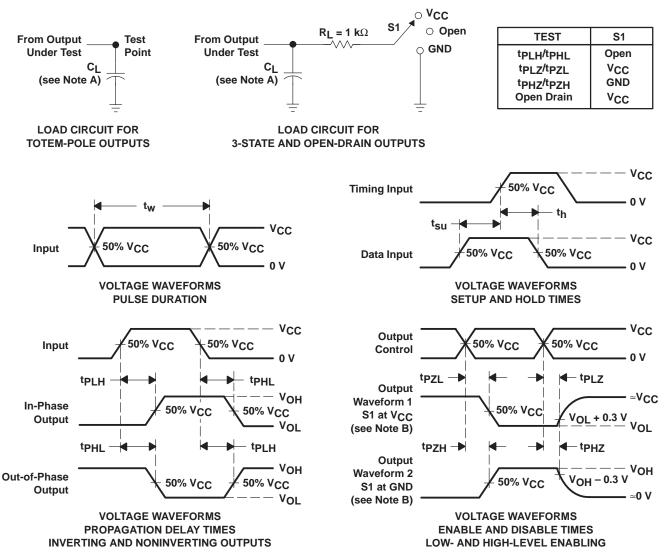
	PARAMETER	FROM	то	LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT
L	PARAIVIETER	(INPUT)	(OUTPUT)		MIN	TYP	MAX	IVIIIN	IVIAA	UNIT
	^t PLH	A or B	V	Y		3.6	5.5	1	6.5	ns
	^t PHL	AOIB	ı			3.6	5.5	1	6.5	115
	^t PLH	A or B	V	C. 50 pF		5.1	7.5	1	8.5	20
	^t PHL	AUB	T	C _L = 50 pF		5.1	7.5	1	8.5	ns

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER			ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	15	pF



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \ \Omega$, $t_f \leq 3 \ ns$.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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